CE 530 Molecular Simulation

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Lecture 16 Dielectrics and Reaction Field Method

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Review

O Molecular models

- *intramolecular terms: stretch, bend, torsion*
- intermolecular terms: van der Waals, electrostatics, polarization

O Electrostatic contributions may be very long-ranged

• monopole-monopole decays as r⁻¹, dipole-dipole as r⁻³ (in 3D)

O Need to consider more than nearest-image interactions

• direct lattice sum not feasible

O Ewald sum

- approximate field due to charges by smearing them
- smeared-charge field amenable to Fourier treatment
- correction to smearing needs only nearest-neighbor sum



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(Infinite) electrically conducting parallel plates separated by vacuum

Apply an electric potential difference $V = \phi_1 - \phi_2$ across them



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Capacitors

The total charge is proportional to the potential difference



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Dielectrics

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O A dielectric is another name for an insulator (non-conductor)O Dielectrics can polarize in the presence of an electric field

• *distribute charges nonuniformly*

O Capacitor with a dielectric inside

Dielectrics

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 - *dielectric sets up an offsetting distribution of charges when field is turned on*



Dielectrics

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O Capacitance is increased

- $C = Q/(V/\varepsilon) = \varepsilon C_0$
- same charge on each plate, but potential difference is smaller
- ε is the dielectric constant ($\varepsilon > 1$) (relative permittivity)

Polarization • The dielectric in the electric field exhibits a net dipole moment M O Every microscopic point in the dielectric also will have a dipole moment O The polarization vector **P** is the dipole moment per unit volume

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- *in general,* $\mathbf{P} = \mathbf{P}(\mathbf{r})$
- for sufficiently small fields, **P** is proportional to the local **E**

 $\mathbf{P} = \chi \mathbf{E}$ χ = electric susceptibility

• this is a key element of linear response theory

Origins of Polarization

O Polarization originates in the electrostatic response of the constituent molecules

O In ionic systems, charges migrate

$$\mathbf{M} = \sum_{i=1}^{N} q_i \mathbf{r}_i$$

E

O In dipolar systems, molecular dipoles rotate

$$\mathbf{M} = \sum_{i=1}^{N} \vec{\mu}_i$$

O In apolar systems, dipoles are induced

"bound charges"





Polarization Charges

O Does polarization imply a nonzero charge density in the dielectric?

• No. For uniform **P**, the charge inhomogeneities cancel



• But for nonuniform **P**, there <u>will</u> be a net charge due to polarization

• In general

$$\rho_{pol} = -\nabla \cdot \mathbf{P}$$

$$P_1$$

$$P_2$$

$$P_2$$
Non-zero net charge

Surface Charge

O At the dielectric surface, the polarization is discontinuous

- *i.e., it is non uniform*
- non-zero net charge at surfaces



Net negative charge

Net positive charge

• charge per unit area is the component of **P** normal to surface

$$\sigma_{pol} = \mathbf{P} \cdot \hat{\mathbf{n}}$$

O Relation between physical constants

- *dielectric constant E describes increased capacitance due to surface charges*
- electric susceptibility χ describes polarization due to electric field, and which leads to the surface charges

Electrostatic Equations for Dielectrics 1.

O Basic electrostatic formula

 $\nabla \cdot \mathbf{E} = \rho$

O Separate "free" charges from polarization charges

$$\nabla \cdot \mathbf{E} = (\rho_{\text{free}} + \rho_{\text{pol}})$$
$$= (\rho_{\text{free}} - \nabla \cdot \mathbf{P})$$

O Apply linear response formula

$$\nabla \cdot \mathbf{E} = (\rho_{\text{free}} - \nabla \cdot (\boldsymbol{\chi} \mathbf{E}))$$
$$\nabla \cdot ((1 + \boldsymbol{\chi}) \mathbf{E}) = \rho_{\text{free}}$$

 $O \rho_{free}$ relates to the electric field with no dielectric (vacuum)

 $\nabla \cdot \mathbf{E}_0 = \rho_{\text{free}}$

O The relation follows

$$\begin{aligned} & (1+\chi)\mathbf{E} = \mathbf{E}_0 \\ & \varepsilon \mathbf{E} = \mathbf{E}_0 \end{aligned} \} \quad \varepsilon = 1 + \chi \end{aligned}$$

 $\begin{array}{c} \underline{\text{Note on notation}} \\ \varepsilon = \varepsilon_0 \Rightarrow \text{``permittivity''} \\ \varepsilon \text{ dim'less} \Rightarrow \text{``dielectric constant'' or} \\ \text{``relative permittivity''} \end{array}$

Electrostatic Equations for Dielectrics

O Equations are same as in vacuum, but with scaled field $\nabla \cdot (\varepsilon \mathbf{E}) = \rho_{\text{free}} \quad \nabla \times (\varepsilon \mathbf{E}) = 0$ constant ε

- O All interactions between "free" charges can be scaled accordingly
 - Coulomb's law in a (linear) dielectric

 $\mathbf{F} = \frac{q_1 q_2}{\varepsilon r^2} \hat{\mathbf{r}}$

 q_1 and q_2 are free charges

O Dielectric boundaries

- ρ_{free} independent of dielectric
- *implies continuity of E* but only normal component

$$\boldsymbol{\varepsilon}^{I} \mathbf{E}_{\perp}^{I} = \boldsymbol{\varepsilon}^{II} \mathbf{E}_{\perp}^{II}$$
$$\mathbf{E}_{\parallel}^{I} = \mathbf{E}_{\parallel}^{II}$$

Thermodynamics and Dielectric Phenomena

- O Fundamental equation in presence of an electric field $d(\beta A) = Ud\beta - \beta PdV + \beta \mu dN - \beta \mathbf{E} \cdot d\mathbf{M} \qquad \mathbf{M} = \text{total dipole moment} \quad \sum \vec{\mu}_i$
 - Analogous to mechanical work $P\Delta V$, creation of dipole moment M in constant field E requires work $E \cdot \Delta M = E \cdot M$

O More convenient to set formalism at constant field E

 $d\beta A' \equiv d\beta (A + \mathbf{E} \cdot \mathbf{M}) \qquad \text{Legendre transform}$ $= Ud\beta - \beta P dV + \beta \mu dN + \mathbf{M} \cdot d\beta \mathbf{E}$ $= Ud\beta - \beta P dV + \beta \mu dN + V \mathbf{P} \cdot d\beta \mathbf{E} \qquad \mathbf{P} = \mathbf{M}/V$

O Electric susceptibility is a 2nd-derivative property

$$\chi = \left(\frac{\partial P_z}{\partial E_z}\right)_{T,V,N} = \frac{1}{V} \left(\frac{\partial^2 A'}{\partial E_z^2}\right)$$

take z as direction of field

Simple Averages 4. Heat Capacity (from Lecture 6)

O Example of a "2nd derivative" property

$$C_{v} = \left(\frac{\partial E}{\partial T}\right)_{V,N} = -k\beta^{2} \left(\frac{\partial^{2}(\beta A)}{\partial \beta^{2}}\right)_{V,N}$$
$$= -k\beta^{2} \frac{\partial}{\partial \beta} \frac{1}{Q(\beta)} \int dr^{N} dp^{N} E e^{-\beta E}$$

O Expressible in terms of fluctuations of the energy

$$C_{v} = k\beta^{2} \left[\left\langle E^{2} \right\rangle - \left\langle E \right\rangle^{2} \right]$$

<u>Note</u>: difference between two $O(N^2)$ quantities to give a quantity of O(N)

O Other 2nd-derivative or "fluctuation" properties

• isothermal compressibility $\kappa_T = -\frac{1}{V} \left(\frac{\partial V}{\partial P}\right)_{T,N}$

Statistical Mechanics and Dielectric Phenomena

O Formula for electric susceptibility

$$\begin{split} \chi &= \left(\frac{\partial P_z}{\partial E_z}\right)_{T,V,N} = \frac{1}{V} \left(\frac{\partial^2 A'}{\partial E_z^2}\right) \\ &= \frac{1}{V} \frac{\partial}{\partial E_z} \left[\frac{1}{Q(E_z)} \int dr^N d\omega^N dp^N M_z e^{-\beta E} e^{\beta E_z M_z}\right] \\ &= \frac{\beta}{V} \left[\left\langle M_z^2 \right\rangle - \left\langle M_z \right\rangle^2 \right] \\ &= \frac{\beta}{DV} \left[\left\langle \mathbf{M}^2 \right\rangle - \left\langle \mathbf{M} \right\rangle^2 \right] \end{split}$$

O Susceptibility is related to fluctuations in the total dipole moment

• this is sensible, since χ describes how "loose" the charges are, how easily they can appear/orient in response to an external field

Dielectric Constant from Molecular Simulation

O Method 1. Ensemble average of dipole fluctuations

$$\varepsilon = 1 + \chi = 1 + \frac{\beta}{DV} \left[\left\langle \mathbf{M}^2 \right\rangle - \left\langle \mathbf{M} \right\rangle^2 \right]$$

$$\mathbf{M} = \sum_{\text{charges, } i} \mathbf{r}_i q_i \qquad \text{or} \qquad \mathbf{M} = \sum_{\text{dipoles, } i} \boldsymbol{\mu}_i$$

O Method 2. Response to an electric field

 $\mathbf{P} = \chi \mathbf{E}$

• Apply field **E**, measure response **P**

Connection to Ewald Sum

- O Surface charges on dielectric produce a non-negligible electric field throughout
 - Local regions inside dielectric feel this field, even though they have no polarization charge
 - Surface charges arise when the system has uniform polarization dipole moment per unit volume
- In simulation of polar systems, at any instant the system will exhibit an instantaneous dipole
 - This dipole is replicated to infinity
 - But in principle it stops at some surface
 - Should the resulting field influence the simulated system?
 - The boundary conditions at infinity are relevant!



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• Consider the simulated system embedded in a continuum dielectric



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- The dielectric responds with a counter charge distribution



- Consider the simulated system embedded in a continuum dielectric
- O An instantaneous dipole fluctuation occurs often during the simulation
- O The polarization makes a surface charge , and field **E**
- The dielectric responds with a surface charge distribution
- This produces a depolarizing field that attenuates the surfacecharge field



Boundary Contribution to Hamiltonian

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O The field due to the surface charge is

$$\mathbf{E}_p = \frac{2\pi}{3} \mathbf{P}$$
 complicated by spherical geometry

O The depolarizing field from the dielectric is

$$\mathbf{E}_d = -\frac{4\pi}{3} \frac{\varepsilon' - 1}{2\varepsilon' + 1} \mathbf{P}$$

• The contribution to the system energy (Hamiltonian) from its interaction with these fields is

$$U_{pol} = -(\mathbf{E}_p + \mathbf{E}_d) \cdot \mathbf{P}$$
$$= \frac{2\pi}{3} \left(1 - \frac{2(\varepsilon' - 1)}{2\varepsilon' + 1} \right) |\mathbf{P}|^2$$

O Common practice is to use conducting boundary, $\varepsilon' = \infty$ $U_{pol} = 0$ Both effects cancel, and we can use the Ewald formula as derived "Tin foil" boundary condition

Reaction Field Method

- O Alternative to Ewald sum for treatment of longrange electrostatic interactions
- O Define interaction sphere **R** for each particle
- O Direct interactions with other particles in \Re
- O Treat material outside sphere as continuum dielectric
 - Dielectric responds to instantaneous dipole inside sphere
 - Contributes to energy as described before

$$U_{rf} = \frac{1}{2} \sum_{i=1}^{N} \mu_i \cdot \left[\frac{2(\varepsilon'-1)}{2\varepsilon'+1} \frac{1}{r_c^3} \sum_{j \in \Re_i} \mu_j \right]$$

• Aim to make $\varepsilon' = \varepsilon$ (results not sensitive to choice)



Summary

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- O Dielectric constant describes increased capacitance associated with insulator placed between parallel plates
- O Insulator responds to an external field by polarizing
- O Polarization leads to surface charge that offsets imposed field
- O Charges at infinitely distant boundary have local effect due to this offsetting field
- If the system is embedded in a conducting medium, it will respond in a way the eliminates the surface-charge effect
- O Susceptibility describes linear relation between polarization and external field
 - 2nd-derivative property related to fluctuations in polarization
- C Reaction field method is a simpler and more efficient alternative to the Ewald sum